NSN 5961-01-068-5868

Transistor - Page 1 of 1

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-068-5868 **Inclosure Material:** Plastic **Overall Length:** Between 0.380 inches and 0.420 inches **Overall Height:** Between 0.140 inches and 0.190 inches Overall Width: Between 0.330 inches and 0.380 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 70.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open and 70.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 15.00 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 30.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead and 1 tab, solder lug **Specification Data:** 80131-release6488 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**